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Thermophysical Properties and Phase Equilibria of Materials Systems R.R. Reeber, D.Brenner, K.Wang and John Prater

The objective is to improve thermal expansion, specific heat, molar volume, and bulk moduli predictions at the highest temperatures and pressures. In those regions experiments are difficult and data is often marginally reliable. In a series of papers, we have developed models for predicting these properties. By considering the influence of thermal defects on thermal expansion it has been possible to provide quantitative relationships for thermal expansion and molar volume from near absolute zero to the melting point for a wide range of oxides, carbides, and metals. Over the course of the project we have combined our improved properties with finite element methods to calculate residual stresses important for the fabrication and reliability of group II-V Nitride devices and cutting tool materials such as tungsten carbide. We provided quantitative expressions for the thermal expansion of important cubic and hexagonal semiconductors (nitrides, phosphides, arsenides etc.) from cryogenic temperatures (approaching 0°K) to near their melting points. A list of publications and presentations follows.

Publications supported by ARO under DAAH04-93-D-0003.

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Conference Talks:

- 1. Wang, K. and R. R. Reeber, Thermoelastic Properties of Group IIA Oxides, The American Ceramic Society 103rd Annual Meeting, Indianapolis, IN, Apr. 22-25, 2001
- 2. Wang, K., W. M. Ashmawi, M. A. Zikry, R. R. Reeber, Deformation and failure modes of thin film layered systems, MRS Fall Meeting, Boston, MA, Nov.27-Dec.1, 2000.
- 3. Reeber, R. R. and K. Wang, High temperature elastic constant prediction of some Group III-Nitrides, MRS Fall Meeting, Boston, MA, Nov.27-Dec.1, 2000.
- 4. Wang, K. and R. R. Reeber, High temperature/pressure thermophysical properties prediction, MRS Spring Meeting, San Francisco, CA, Apr. 24-28, 2000.
- 5. Ashmawi, W. M., K. Wang, R. R. Reeber, M. A. Zikry, Design guidelines for thin film layered systems, *MRS Spring Meeting*, San Francisco, CA, Apr. 24-28, 2000.
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- 15. Reeber, R. and K. Wang, High temperature/pressure expansion of elemental semiconductors and tungsten, 20th Army Science Conference, Norfolk, Virginia, June, 1996
- 16. Reeber, R.R. and K. Wang, Lattice parameters and thermal expansion of 6-H SiC, *The American Ceramic Society Annual meeting* April 2002, St. Louis, Mo.

Work completed in 2002.

The work of thermoelastic properties of Group IIA oxides at high temperature/pressure is almost finished and is in the process of being written up for journal publication. The thermal expansion at high temperatures was estimated and predicted with our earlier model. The elastic constants of these oxides have been predicted by a corresponding relationship where directional characteristic temperature model was utilized. Excellent agreement with available data was obtained.

The work on lattice parameter and thermal expansion of SiC has been completed. The data processing of neutron powder diffraction experiments at the NIST National reactor facility is finished. The interpretation of our low temperature experimental data with other author's results in high temperatures and the results were presented as an invited paper at the April 2002 Ceramic Society Annual Meeting in St. Louis, Mo.

List of personnel supported on the project:

Mr. W. Ashmawi, Mechanical Engineering graduate student

Dr. Kai Wang, Adjunct Assistant Professor

Dr. Robert Reeber Adjunct Research Professor

Dr. Donald Brenner, Associate Professor

Report of inventions:

none